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Application Note

On-Chip FLASH Programming Routines

For MC68HC908LB8, MC68HC908QL4, MC68HC908QB8, MC68HC908QB4, MC68HC908QY8, and MC68HC908QY4A Series¹

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Introduction

This application note applies to the MC68HC908LB8, MC68HC908QL4, MC68HC908QB4/QB8/QY8, and MC68HC908QY4A Series¹ FLASH-based microcontroller units (MCUs). To program, erase, and verify FLASH, these MCUs have on-chip FLASH support routines residing in ROM (read-only memory). These routines may be accessed in either user mode or monitor mode and eliminate the need to develop separate FLASH routines for applications.

This application note describes how to call each of the routines in user software, what is performed, and what is returned as confirmation of routine execution. The software files are available as a zip file, AN2635SW, from the Freescale Semiconductor website: www.freescale.com

NOTE

With the exception of mask set errata documents, if any other Freescale Semiconductor document contains information that conflicts with the information in the device data sheet, the data sheet should be considered to have the most current and correct data.

1. MC68HC908QY4A Series includes MC68HC908QY4A, MC68HC908QY2A, MC68HC908QY1A, MC68HC908QT4A, MC68HC908QT2A, MC68HC908QT1A

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Routines Supported in ROM

FLASH Overview

The FLASH cell used on these 0.5- μ MCUs is an industry-proven split-gate cell. The cell uses channel hot electron injection for programming and Fowler-Nordheim tunnelling for erasing. All programming voltages are generated internally by a charge pump from a single connection to V_{DD}.

With the quick byte-programming time and the organization of the FLASH array into 32-byte rows, the entire 8-Kbyte memory can be programmed in less than one-half second. This type of FLASH is specified to withstand at least 10,000 program/erase cycles and has enhanced reliability over previous technology.

Usually, split-gate FLASH is programmed on a row basis and erased on a page basis. Also, an entire specified array can be mass erased. For the target MCUs, rows are 32 bytes and pages are 64 bytes (two rows of 32 bytes each).

Routines Supported in ROM

In the ROM, six routines are supported. Because the ROM has a jump table, the user does not call the routines with direct addresses. Therefore, the calling addresses will not change—even when the ROM code is updated in the future.

This section introduces each routine briefly. Details are discussed in later sections.

GetByte

This routine is used to receive a byte serially on the general-purpose I/O PTA0. The receiving baud rate is the same as the baud rate used in monitor mode. In the GetByte routine, the GetBit routine is called to generate baud rates required for each MCU.

PutByte

This routine is used to send a byte serially on the general-purpose I/O PTA0. The sending baud rate is the same as the baud rate specified in monitor mode.

RDVRRNG

This routine is used to perform one of two options. Using the send-out option, this routine reads FLASH locations and sends the data out serially on the general-purpose I/O PTA0. Using to verify option, this routine verifies the FLASH data against data in a specific RAM location, which is referred to as a DATA array.

PRGRNGE

This routine is used to program a contiguous range of FLASH locations that is up to 32 bytes and in the same row. Programming data is first loaded into the DATA array. PRGRNGE can be used when the internal operating frequency (f_{op}) is between 1.0 MHz and 8.4 MHz.

ERARNGE

This routine is used to erase either a page (64 bytes) or the whole array of FLASH. It can be used when the internal operating frequency (f_{op}) is between 1.0 MHz and 8.4 MHz.

DELNUS

This routine can generate a specified delay based on the values of register X and accumulator (A) as parameters. DELNUS is used in ERARNGE routine.

Variables Used in the Routines

The RDVRNGE, PRGRNGE, and ERARNGE routines require certain registers and/or RAM locations to be initialized before calling the routines in the user software. Table 1 shows variables used in the routines and their locations.

Location	Variable Name	Size (Bytes)	Description
RAM – RAM+7	Reserved	8	Reserved for future use
RAM+\$8	CTRLBYT	1	Control byte setting erase size
RAM+\$9	CPUSPD	1	CPU speed — the nearest integer of f_{op} (in MHz) \times 4; for example, if f_{op} = 2.4576 MHz, CPUSPD = 10
RAM+\$A, RAM+\$B	LADDR	2	Last address of a 16-bit range
RAM+\$C	DATA	Varies	First location of DATA array; DATA array size must match a programming or verifying range
Registers H:X	—	2	Beginning address of a 16-bit range

	Table 1.	Variables	and Their	Locations
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RAM

In general, RAM in Table 1 indicates the RAM start address. See Table 2 for RAM start locations for specific MCUs. For example, the RAM start address for the MC68HC908LB8 (and each MCU currently in the table) is \$80.

CTRLBYT

The control byte (CTRLBYT) is located at RAM address RAM+\$8 and is used for the ERARNGE routine. In the case of the MC68HC908LB8, the CTRLBYT is located at \$88. Bit 6 in this location is used to specify either MASS (1) or PAGE (0) erase. The other bits must be 0. If one or more of these bits (except bit 6) is initialized with 1, the erase operation is not executed.

CPUSPD

To set up proper delays used in the PRGRNGE and ERARNGE routines, a value indicating the internal operating frequency (f_{op}) must be stored at CPUSPD, which is located at RAM address RAM+\$9. In the case of the MC68HC908LB8, the CPUSPD is located at \$89. The CPUSPD value is the nearest integer of f_{op} (in MHz) times 4. For example, if f_{op} is 4.2 MHz, the CPUSPD value is 17. If f_{op} is 2.1 MHz, the CPUSPD value is 8. Setting a correct CPUSPD value is very important to program or erase the FLASH successfully.

LADDR

A range specifies the FLASH locations to be read, verified, or programmed. The 16-bit value in RAM addresses RAM+\$A and RAM+\$B holds the last address of a range. The addresses RAM+\$A and RAM+\$B are the high and low bytes of the last address, respectively. In the case of MC68HC908LB8, the LADDR is located at \$8A and \$8B. LADDR is used for RDVRRNG and PRGRNGE routines.

DATA

DATA is the first location of the DATA array and is located at RAM address RAM+\$C. For the MC68HC908LB8, the DATA is located at \$8C. The array is used for loading program or verify data. The DATA array must be in the zero page and its size must match the size of the range to be programmed or verified.

Registers H:X

In the RDVRRNG and PRGRNGE routines, registers H and X are initialized with a 16-bit value representing the first address of a range. High and low bytes of the address are stored to registers H and X, respectively. In the ERARNGE routine, registers H and X are initialized with an address which is within the page or entire array to be erased.

How to Use the Routines

This section describes the details of each routine. Table 2 provides necessary addresses used in the on-chip FLASH routines for each MCU type. Table 3 summarizes the six routines.

MCU Name	RAM	GetByte	PutByte	RDVRRNG	PRGRNGE	ERARNGE	DELNUS
MC68HC908LB8	\$80	\$037E	\$0381	\$0384	\$038A	\$0387	\$038D
MC68HC908QL4	\$80	\$2B7E	\$2B81	\$2B84	\$2B8A	\$2B87	\$2B8D
MC68HC908 QY4A Series ⁽¹⁾	\$80	\$2800	\$280F	\$2803	\$2809	\$2806	\$280C
MC68HC908 QB4/QB8, MC68HC908 QY8	\$80	\$2800	\$280F	\$2803	\$2809	\$2806	\$280C

Table 2. MCU Type vs. Necessary Addresses Required for On-Chip FLASH Routines

NOTES:

1. MC68HC908QY4A Series includes MC68HC908QY4A, MC68HC908QY2A, MC68HC908QY1A, MC68HC908QT4A, MC68HC908QT2A, MC68HC908QT1A

	GetByte	PutByte	RDVRRNG	PRGRNGE	ERARNGE	DELNUS
Routine Description	Get a data byte serially through PTA0	Send a data byte serially through PTA0	Read and/or verify a FLASH range	Program a FLASH range (maximum 32 bytes in a row)	Erase a PAGE or entire array	$\begin{array}{c} \text{Generate} \\ \text{delay} \\ 3 \times \text{A} \times \text{X} + 8 \\ (\text{cycles}) \end{array}$
Internal Operating Frequency (f _{op})	_			1 MHz to 8.4 MHz	1 MHz to 8.4 MHz	_
Hardware Requirement	Pullup on PTA0	Pullup on PTA0	For send-out option, pullup on PTA0	N/A	N/A	N/A
Entry Conditions	PTA0: Input (DDRA0 = 0)	PTA0: Input and 0 data bit (DDRA0 = 0, PTA0 = 0) A: data to be sent	 H:X: First address of range LADDR: Last address of range A: A = \$00 for send-out option or A ≠ \$00 for verify option For send-out option PTA0: Input and 0 data bit (DDRA0 = 0, PTA0 = 0) For verify option, DATA array: Load data to be verified against FLASH read data 	H:X: First address of range LADDR: Last address of range CPUSPD: the nearest integer f _{op} (in MHz) times 4 Data array: Load data to be programmed	H:X: Address within a page or an array to be erased CPUSPD: the nearest integer f _{op} (in MHz) times 4 CTRLBYT: \$40 = MASS erase \$00 = PAGE erase	A: Value between 4 and 255 X: Value between 1 and 255

	GetByte	PutByte	RDVRRNG	PRGRNGE	ERARNGE	DELNUS
Exit Conditions	A: Data received through PTA0 C-bit: Framing error indicator (error: C = 0)	A, X: No change PTA0: Input and 0 data bit (DDRA0 = 0, PTA0 = 0)	A: Checksum H:X: Next FLASH address C-bit: Verify result indicator (success: C = 1) DATA array: Data replaced with FLASH read data (verify option)	H:X: Next FLASH address	H:X: No change	
l Bit				I bit is set	I bit is set	_
СОР	Not Serviced	Not Serviced	Serviced	Serviced	Serviced	Not Serviced
Subroutines Called	GetBit	_	PutByte for send-out option	_	DELNUS	_
RAM Variable		_	LADDR (2 bytes), DATA array (no size limitation as long as in the zero page)	CPUSPD, LADDR (2 bytes), DATA array (maximum 32 bytes)	CTRLBYT, CPUSPD	_
Stack Used (Including the Routine's Call)	6 bytes	4 bytes	9 bytes for verify option 11 bytes for send-out option	9 bytes	7 bytes	3 bytes

Table 3. Summary of On-Chip FLASH Support Routines (Continued)

GetByte

GetByte is a routine that receives a byte on the general-purpose I/O PTA0, and the received value is returned to the calling routine in the accumulator (A). This routine is also used in monitor mode so that it expects the same non-return-to-zero (NRZ) communication protocol and baud rates.

This routine detects a framing error when a STOP bit is not detected. If the carry (C) bit of the condition control register (CCR) is cleared after returning from this routine, a framing error occurred during the data receiving process. Therefore, the data in A is not reliable. The user software is responsible for handling such errors.

Interrupts are not masked (the I bit is not set) and the COP is not serviced in the GetByte routine. User software should ensure that interrupts are blocked during character reception.

To provide a specific communication baud rate, GetByte calls the GetBit subroutine. In the GetByte routine, two different clock sources, internal clock and external clock, are supported. For example, the MC68HC908LB8 usually has a trimmed internal bus clock of 4 MHz and an external bus clock of 2.4576 MHz. For the MCU to distinguish which clock source is currently selected, the ECGST (external clock generator status) bit in the OSCSTAT (oscillator status register) is monitored in the GetBit subroutine. When ECGST bit is set, the external clock is selected as a clock source. When the bit is cleared, the internal clock is selected.

The baud rate is defined by f_{op} divided by a constant value, which is specified in the development support section in the device data sheet. In the case of the MC68HC908LB8, the baud rate of an internal clock source is defined by f_{op} divided by 417. If the internal bus clock is 4 MHz, the baud rate is 4 MHz/417 = 9592. Therefore, the closest PC baud rate is 9600. On the other hand, the baud rate of an external clock source is f_{op} divided by 256. When an external bus clock is 2.4576 MHz, the baud rate is 2.4576 MHz/256 = 9600.

To use this routine, some hardware setup is required. The general-purpose I/O PTA0 must be pulled up. For more information, refer to the development support section in the device data sheet.

Entry Condition

PTA0 — This pin must be configured as an input and pulled up in hardware.

Exit Condition

A — Contains data received from PTA0.

C bit — Usually the C bit is set, indicating proper reception of the STOP bit. However, if the C bit is clear, a framing error occurred. Therefore, the received byte in A is not reliable.

Example 1: Receiving a Byte Serially

Example 1 shows how to receive a byte serially on PTA0:

GetByte	equ	\$037E	;LB8 GetByte jump address
	bclr	0,DDRA0	;Configure port A bit 0 as an input
	2	GetByte FrameError	;Call GetByte routine ;If C bit is clear, framing error ; occurred. Take a proper action

NOTE

After GetByte is called, the program will remain in this routine until a START bit (0) is detected and a complete character is received.

PutByte

PutByte is a routine that receives a byte on the general-purpose I/O PTA0. The sent value must be loaded into the accumulator (A) before calling this routine. This routine is also used in the monitor mode. Therefore, it uses the same non-return-to-zero (NRZ) communication protocol. The communication baud rates are the same as those described in GetByte.

To use this routine, some hardware setup is required. The general-purpose I/O PTA0 must be pulled up and configured as an input and the PTA0 data bit must be initialized to 0.

Interrupts are not masked and the COP is not serviced in the PutByte routine. User software should ensure that interrupts are blocked during character transmission.

Entry Condition

A — Contains data sent from PTA0

PTA0 — This pin must be configured as an input and pulled up in hardware and the PTA0 data bit must be initialized to 0.

Exit Condition

A and X — are restored with entry values.

Example 2: Sending a Byte Serially

Example 2 shows how to send a byte (\$55) serially on PTA0:

```
PutByte equ $0381 ;LB8 PutByte jump address
bclr 0,DDRA ;Configure port A bit 0 as an input
bclr 0,PTA ;Initialize data bit to zero PTA0=0
lda #$55 ;Load sent data $55 to A
jsr PutByte ;Call PutByte routine
```

RDVRRNG

When using the RDVRRNG routine, the user must select one of the following function options:

- Send-out option Used to read a range of FLASH locations and to send the read data to a host through PTA0 by using the PutByte routine.
- Verify option Used to read a range of FLASH locations and to verify the read data against the DATA array.

Send-Out Option

If the accumulator (A) is initialized with \$00 at the routine entry, the read data will be sent out serially through PTA0. The communication baud rate is the same as the baud rate described in the PutByte routine. When this option is selected, the PTA0 must be pulled up and configured as an input and the PTA0 data bit must be initialized to 0.

Verify Option

If A is initialized with a non-zero value, the read data is verified against the DATA array for each byte of FLASH and the DATA array is replaced by the data read from FLASH. If the data does not match the corresponding value, the data read from FLASH can be confirmed in the DATA array. All data in the DATA array must be in the zero page, but a range can be beyond a row size or a page size.

Carry (C) Bit and Checksum

The first and last addresses of the range to be read and/or verified are specified as parameters in registers H:X and LADDR, respectively. In the verify option, the carry (C) bit of the condition code register (CCR) is set if the data in the specified range is verified successfully against the data in the DATA array. However when the send-out option is selected, the status of the C bit is meaningless because this function does not include the verify operation. Both options calculate a checksum on data read in the range. This checksum, which is the LSB of the sum of all bytes in the entire data collection, is stored in A upon return from the function.

Interrupts are not masked. The COP is serviced in RDVRRNG. The first COP is serviced at 23 bus cycles after this routine is called in the user software. However, the COP timeout might still occur in the send-out option if the COP is configured for a short timeout period.

Entry Condition

H:X — Contains the beginning address in a range.

LADDR — Contains the last address in a range.

A — When A contains \$00, read data is sent out via PTA0 (send-out option is selected). When A contains a non-zero value, read data is verified against the DATA array (verify option is selected).

DATA array — Contains data to be verified against FLASH data. For the send-out option, the DATA array is not used.

PTA0 — When the send-out option is selected, this pin must be configured as an input and pulled up in hardware and PTA0 must be initialized to 0.

Exit Condition

A — Contains a checksum value.

H:X — Contains the address of the next byte immediately after the range read.

C bit — Indicates the verify result (only applies to the verify option).

When the C bit is set, the verify succeeded.

When the C bit is cleared, the verify failed.

DATA array — Replaced with data read from FLASH when the verify option is selected.

Example 3: Verify Option

Example 3 shows how to use the verify option:

RDVRRNG (equ	\$0384	;LB8 RDVRRNG jump address
-	lda		;Index offset into DATA array ;Initial data value to store in array
Data_load			
	coma		
2	sta	DATA, x	;Fill DATA array, 32 bytes data, ; to verify against programmed FLASH
á	aix	#1	; data (In this example verifying data
c	cphx	#\$20	; is \$55, \$AA, \$55, \$AA)
ł	bne	Data_load	
-	ldhx	#\$C01F	;Load last address of range to
5	sthx	LADDR	; LADDR
-	ldhx		;Load beginning address of range ; to H:X
-	lda	#\$55	;Write non-zero value to A to select ; the verify option
-	jsr	RDVRRNG	;Call RDVRRNG routine
ł	bcc	Error	;If bit C is cleared, verify failed
			; Take a proper action
			; A contains a checksum value

Example 4: Send-Out Option

Example 4 shows how to use the send-out option:

RDVRRNG	equ	\$0384	;LB8 RDVRRNG jump address
	bclr ldhx sthx	0,DDRA 0,PTA #\$C025 LADDR	;Configure Port A bit 0 as an input ;Initialize data bit to zero PTA0=0 ;Load last address of range to ; LADDR
	ldhx	#\$C010	;Load beginning address of range ; to H:X ;A=0 to select send-out option
	jsr	RDVRRNG	;Call RDVRRNG routine ; A contains a checksum value

PRGRNGE

PRGRNGE is used to program a range of FLASH locations with data loaded into the DATA array. The range must be less-than or equal-to 32 bytes. All bytes that will be programmed must be in the same row. Programming data is passed to PRGRNGE in the DATA array. The size of the DATA array must match the size of a specified programming range. This routine supports an internal operating frequency between 1.0 MHz and 8.4 MHz.

For this split-gate FLASH, the programming algorithm requires a programming time (t_{prog}) between 30 µs and 40 µs. (Refer to the FLASH memory section in the device data sheet.) Table 4 shows how t_{prog} is adjusted by a CPUSPD value in this routine. The CPUSPD value is the nearest integer of f_{op} (in MHz) multiplied by 4. For example, if f_{op} is 2.4576 MHz, the CPUSPD value is 10 (\$0A). If f_{op} is 8.0 MHz, the CPUSPD value is 32 (\$20).

	Operating Bus Freq. (f _{op})	CPUSPD	t _{prog} (Cycles)	t _{prog}
Case 1	$1.0 \text{ MHz} \leq f_{Bus} < 1.125 \text{ MHz}$	4	38	33.8 μ s < t _{prog} ≤ 38.0 μ s
Case 2	$1.125 \text{ MHz} \le f_{Bus} \le 8.4 \text{ MHz}$	5 to 34	8 x CPUSPD + 5	32.1 μ s \leq t _{prog} \leq 40.0 μ s

Table 4. tprog vs. Bus Frequency

In PRGRNGE, the high programming voltage time is enabled for less than 125 μ s when programming a single byte at any operating bus frequency between 1.0 MHz and 8.4 MHz. Therefore, even when a row is programmed by 32 separate single-byte programming operations, the cumulative high voltage programming time is less than the maximum t_{HV} (4 ms). The t_{HV} is defined as the cumulative high voltage programming time to the same row before the next erase. For more information, refer to the memory characteristics in the electrical specifications section of the device data sheet.

This routine does not confirm that all bytes in the specified range are erased prior to programming. Nor does this routine perform a verification after programming, so there is no return confirmation that programming was successful. To program data successfully, the user software is responsible for these

verifying operations. The RDVRRNG routine can be used to verify a programmed FLASH range against the DATA array.

Interrupts are masked and the COP is serviced in this routine. The first COP is serviced at 59 bus cycles after this routine is called in the user software.

Entry Condition

H:X — Contains the beginning address in a range.

LADDR — Contains the last address in a range.

CPUSPD — Contains the nearest integer value of f_{op} (in MHz) times 4.

DATA array — Contains the data values to be programmed into FLASH.

Exit Condition

H:X — Contains the address of the next byte after the range just programmed.

Example 5: Programming a Row

Example 5 shows how to program one full 32-byte row:

PRGRNGE	equ	\$038A	;LB8 PRGRNGE jump address
Data loa	lda	#\$0000 #\$AA	;Index offset into DATA array ;Initial data value (inverted)
Data_106	coma	DATA, x	;Alternate between \$55 and \$AA ;Fill DATA array, 32 bytes data, ; values to program into FLASH
	aix cphx bne		; (ie. 55, AA, 55, AA)
	ldhx sthx	#\$0A,CPUSPD #\$C01F LADDR #\$C000	<pre>;fop = 2.4576MHz in this example ;Load last address of the row ; to LADDR ;Load beginning address of the ; row to H:X</pre>
	jsr	PRGRNGE	;Call PRGRNGE routine

Example 6: Programming a Range Smaller than a Row

PRGRNGE can be used to program a range less than 32 bytes. Example 6 shows how to program \$55 and \$AA at location \$E004 and \$E005, respectively.

PRGRNGE equ \$038A ;LB8 PRGRNGE jump address mov #\$55,DATA mov #\$AA,DATA+1 mov #\$18,CPUSPD ;fop = 6.0MHz in this example ldhx #\$E005 ;Load last address to LADDR sthx LADDR ldhx #\$E004 ;Load beginning address to H:X jsr PRGRNGE ;Call PRGRNGE routine

ERARNGE

ERARNGE can be called to erase a page (64 bytes) or a whole array of FLASH. Registers H and X can be any address within the page or array to be erased. To select erase size, CTRLBYT is used. Writing \$40 to CTRLBYT selects the entire array (MASS) erase. Writing \$00 to CTRLBYT selects the page erase. When other values are written to CTRLBYT, the erase operation is not executed. This routine supports an internal operating frequency between 1.0 MHz and 8.4 MHz.

In this routine, both PAGE erase time (t_{Erase}) and MASS erase time (t_{MErase}) are set between 4 ms and 5.5 ms. The CPUSPD value is the nearest integer of f_{op} (in MHz) times 4. For example if f_{op} is 3.1 MHz, the CPUSPD is 12 (\$0C). If f_{op} is 4.9152 MHz, the CPUSPD is 20 (\$14).

Interrupts are masked and the COP is serviced in ERARNGE. The first COP is serviced on (40+3xCPUSPD) bus cycles after this routine is called in the user software.

Entry Condition

CTRLBYT — For MASS erase, write \$40. For PAGE erase, write \$00.

H:X — Contains an address within a desired erase page or an array.

CPUSPD — Contains the nearest integer value of f_{op} (in MHz) times 4.

Exit Condition

None

Example 7: Erasing an Entire Array

Example 7 shows how to erase an entire array:

ERARNGE	equ	\$0387	;LB8 ERARNGE jump address
	mov ldhx	#\$08,CPUSPD #\$40,CTRLBYT #\$E000 ERARNGE	;fop = 2.0MHz in this example ;Select Mass erase operation ;Load any FLASH address to H:X ;Call ERARNGE routine

Example 8: Erasing a Page

Example 8 shows how to erase a page from \$E100 through \$E13F:

ERARNGE	mov mov ldhx	#\$14,CPUSPD #\$00,CTRLBYT #\$E121	;LB8 ERARNGE jump address ;fop = 4.9152MHz in this example ;Select Page erase operation ;Load any address within the ; page to H:X
	jsr	ERARNGE	;Call ERARNGE routine

If the FLASH locations that you want to erase are protected due to the value in the FLASH block protect register (FLBPR), the erase operation will not be successful. However when a high voltage (V_{tst}) is applied to the IRQ pin, the block protection is bypassed.

When the FLASH security check fails in the normal monitor mode, the FLASH can be re-accessed by erasing the entire FLASH array. To override the FLASH security mechanism and erase the FLASH array using this routine, registers H and X must contain the address of the FLASH block protect register (FLBPR).

DELNUS

DELNUS is a delay routine used in support of the ERARNGE routine. It can, however, be called independently in the user software. DELNUS uses two parameters stored in the accumulator (A) and the X register (X). Neither of these parameters is passed as an absolute value. The total delay (cycles) resulting from this routine is:

 $DELNUS = 3 \times (A \text{ value}) \times (X \text{ value}) + 8 \text{ cycles}$

where a value of A is 4 or greater and a value of X is 1 or greater. In the ERARNGE routines, the CPUSPD value (which is a frequency parameter) is loaded into A.

Because this routine is called from a jump table, three additional cycles are included in the above equation.

Interrupts are not masked and the COP is not serviced in DELNUS.

Initialization

A — Select A value between 4 and 255

X — Select X value between 1 and 255

Exit Condition

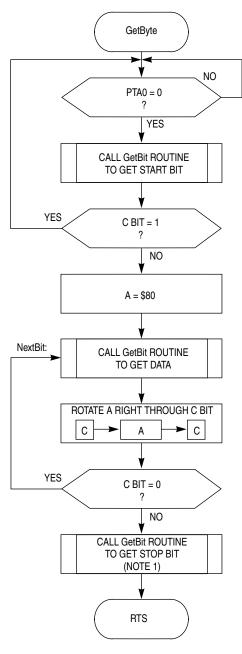
None

Example 9: Generating a Delay

Initialized A = 16 and X = 8 to generate 100 μ s delay at f_{op} = 4 MHz

DELNUS equ \$038D ;LB8 DELNUS jump address lda #\$10 ;[2]A=16 ldx #\$08 ;[2]X=8 jsr DELNUS ;[4]Call DELNUS routine

In this example, the total delay time is $8 + (3 \times 16 \times 8 + 8)$ cycles = 400 cycles (100 µs).



NOTES:

1. When C bit is 0, communication has a framing error.



On-Chip Routines Flowcharts

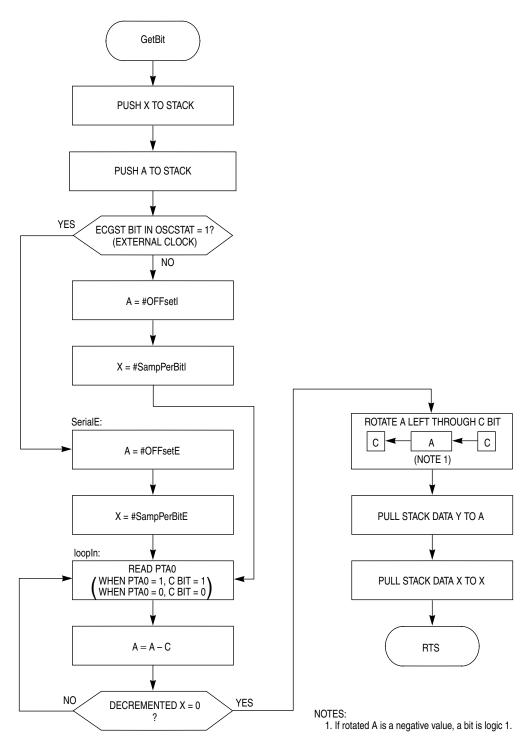
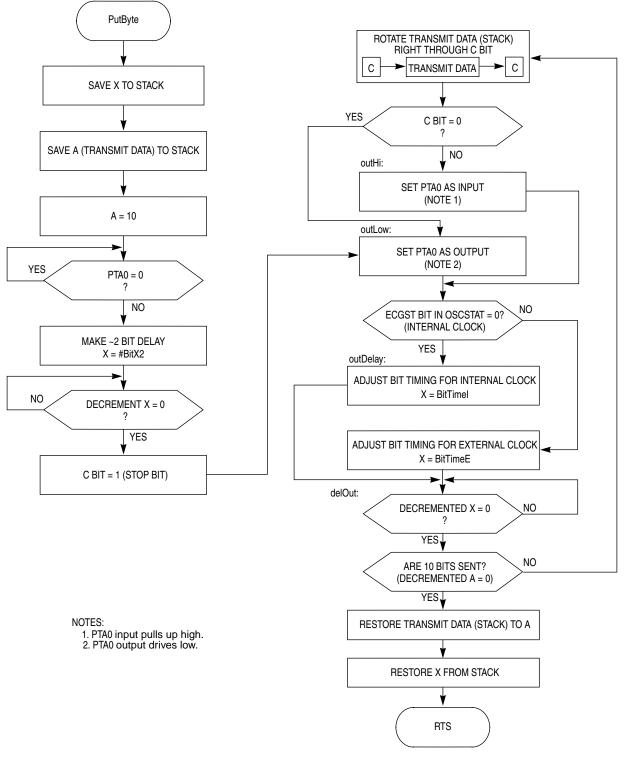
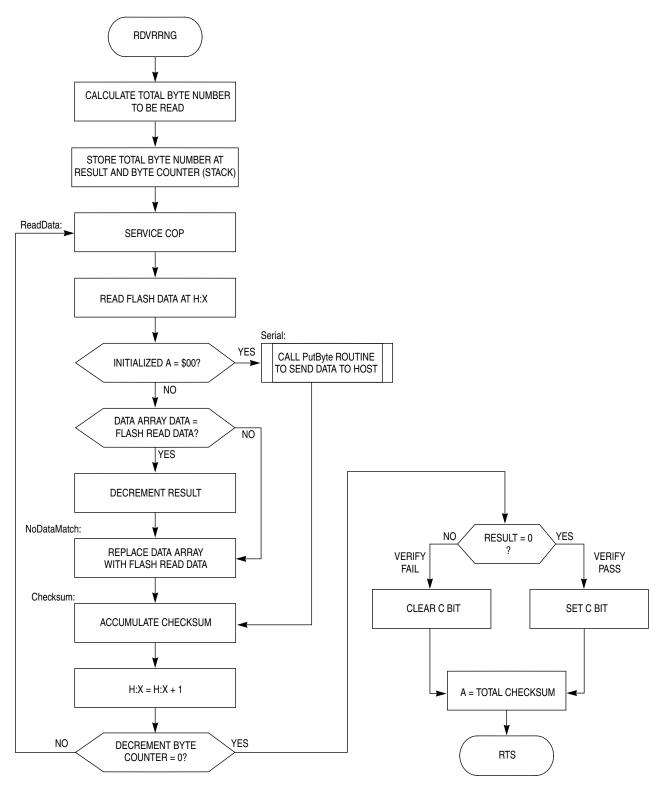


Figure 2. GetBit Routine









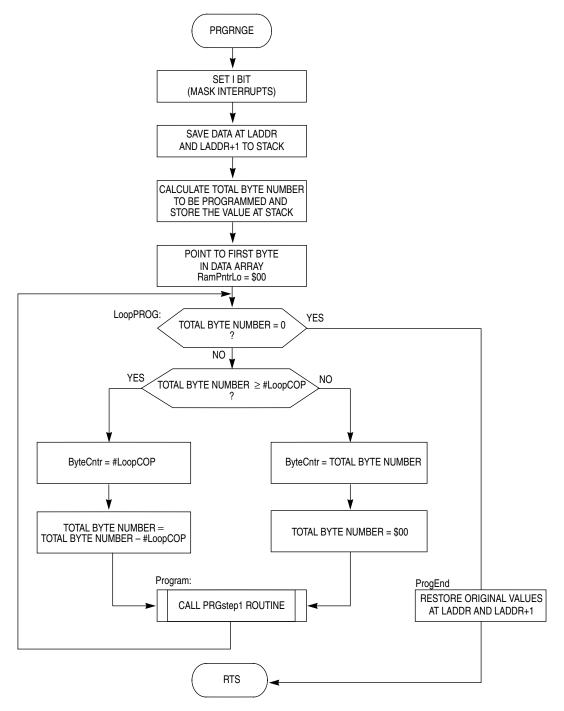


Figure 5. PRGRNGE Routine, Part 1

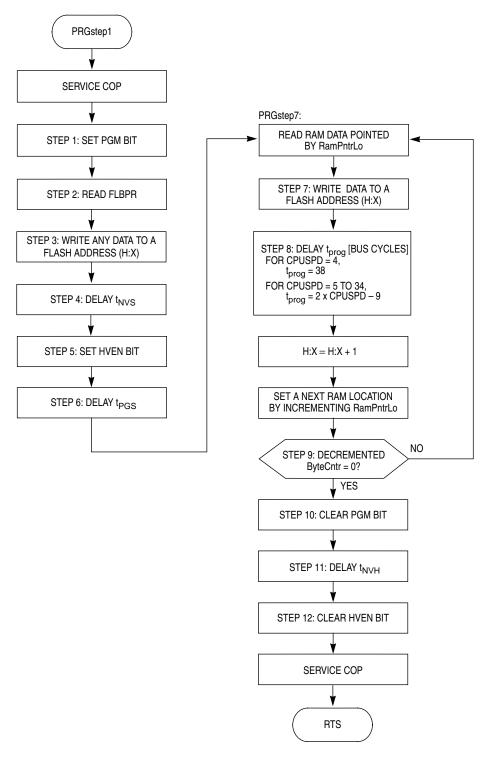
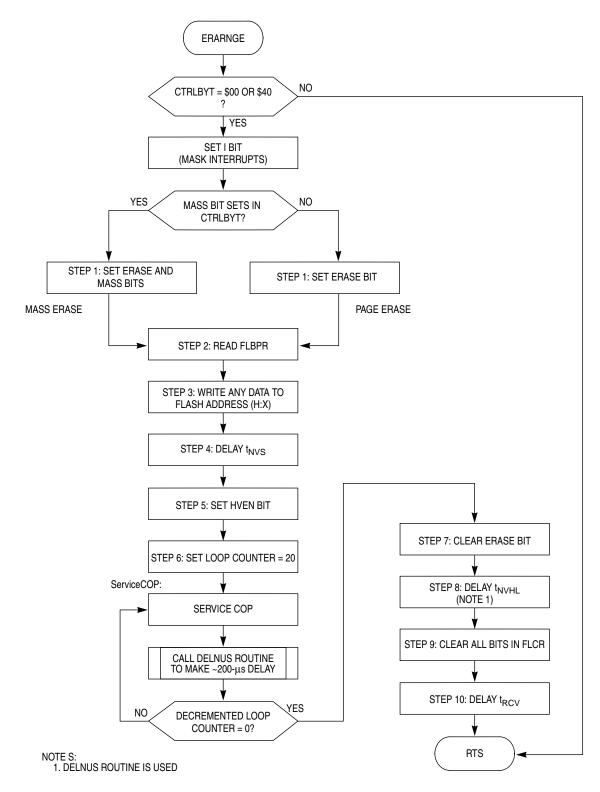


Figure 6. PRGRNGE Routine, Part 2





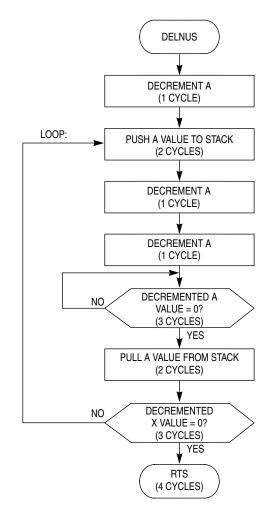


Figure 8. DELNUS Routine

The following source code is for the MC68HC908LB8 on-chip routines. Because other MCUs support different communication baud rates, GetBit and PutByte routines are slightly different. However, these routines are built in the same manner.

```
.pagewidth
       98t
;* PURPOSE: This program has the HC908LB8 FLASH program, erase, verify
;*
        routines and serial communication routines.
;*
;* TARGET DEVICE: HC908LB8
;*
;* ASSEMBLER: P&E Microsystems CASM08Z
;* VERSION: 3.16
;*
;* GENERAL CODING NOTES:
;* A standard equate file "908LB86vXrY.inc" is used to define all MCU
;* register and bit names. Bit names use all uppercase characters.
;* BCLR, BSET, BRCLR, and BRSET use the bit name alone while logical
;* instructions such as ORA use the bit name with a prefix of
;* lowercase "m" which is a bit position mask.
;* ASSEMBLER DIRECTIVES
;* (BASE, MACROS, SETS, CONDITIONS, ETC.)
base
             10t
                   ;Change default to decimal
;* INCLUDED FILES
$NOLIST
      include "908LB8v0r2.inc"
$LIST
;* EQUATES for ROM Assigned Locations
;* ROM Assigned Location
;*
JumpTable:
         equ
             $037E
                       ;jump table start address
FlashROM:
         equ
             JumpTable+$1B ;FLASH ROM start address
;* EQUATES and VARIABLES for GetBit and PutByte routines
;* Constants used in the GetBit and PutByte routines:
;* NOTE: changing the following parameters will alter the baud rate!
;* External clock (Ext) values set for 9600 baud @ 2.4576MHz bus rate
  Internal clock (Int) values set for 9600 baud @ 4.0MHz bus rate
;*
*******
SampPerBitE: equ
             22
                      ;samples per bit time (Ext)
SampPerBitI: equ
             38
                     ;(Int) used in GetBit
           15
OffsetE: equ
                      ;~70% SampPerBit (Ext) and (Int)
             27
OffsetI:
        equ
                      ; used in GetBit
```

On-Chip FLASH Programming Routines, Rev. 4				
	org	FlashROM		

* ROUTINES				

NUSDEL:	jmp	DELNUS	;generate delay	
RNGEPRG:	jmp	PRGRNGE	;program FLASH	
RNGEERA:	jmp	ERARNGE	;erase FLASH	
RNGRDVR:	jmp	RDVRRNG	;read/verify FLASH data	
BytePut:	jmp	PutByte	;send one byte data to a host	
ByteGet:	jmp	GetByte	;receive one byte data from a host	
	org	JumpTable		
,		* * * * * * * * * * * * *	**********	
, ;* JUMP TABL				
********	* * * * * * * *	* * * * * * * * * * * * *	*****	
2002001.	~ <u>1</u> u	÷	; to zero	
LoopCOP:	equ	6	; = 3*SPUSPD*TNVHL+19 (bus cycles) ;COP is serviced when LoopCOP reaches	
TNVHL:	equ	9	; 3*CPUSPD*TERASE+26 (bus cycles) ;FLASH high-voltage hold time (>= 100us)	
TERASE:	equ	17	<pre>; =20+(EraseLOOP*(3*CPUSPD*TERASE+26)) ;FLASH erase time between COP service ; COP is serviced every ~200 us =</pre>	
;* These time LoopErase:	es are s equ	for use by ER 20	;total Terase time (~ 4ms)	
		_		
ByteCntr:	equ	LADDR+1	; FRGRNGE FOULTHE ;LADDR+1 loc. reused as Byte Count in ; PRGRNGE routine	
RamPntrLo:	equ	LADDR	; on a device ;LADDR loc. reused as RAM pointer in ; PRGRNGE routine	
DATA:	rmb	ROWSIZE	;allocation/use of this space depends ; on a device	
LADDR:	rmb	2	;last address	
CPUSPD:	rmb	1	;CPU bus speed (nearest integer of ; bus freq (in MHz) * 4)	
			; selection	
;* The follow CTRLBYT:	wing vai rmb	riables set b 1	y user ;control byte for erase operation	
•* mba fall-	org	DATSTRC	N. NGOY	
ROWSIZE:	equ	32	;FLASH ROW size	
MASSBIT:	equ	6	; RAM for future requirement ;MASS bit of CTRLBYT located in bit 6	
DATSTRC:	equ	RamStart+8	;leave 8-byte offset from start of	
		ABLES for FLA ******	SH routines ************************************	
,			************	
BrkTimeI:	equ	123	; and (Int) used in EchoBrk	
BrkTimeE:	-	232	;delay count for 10 bit times (Ext)	
BitTimeI:	equ	129	; (Int) used in PutByte	
BitTimeE:	equ	76	;delay count for 1 bit time (Ext) and	
;* 2 bit time	e is not	accurate		
BitX2:	equ	210	;delay count for ~2 bit times	
•* moro than	Offect	camplog - 1	means bit is detected as a logic 1	

;* NAME: GetByte ;* PURPOSE: ;* Get one byte data through PTAO serially. This routine supports ;* a baud rate 9600 bps at internal 4MHz and external 2.4576MHz bus ;* frequencies. A clock is distinguished by the state of ECGST bit (bit 0) in OSCSTAT. When ECGST=1, an external clock is selected. ;* ;* ENTRY CONDITIONS: ;* PTA0 configured as an input. ;* EXIT CONDITIONS: ;* A contains a byte received when START bit is detected ;* C-bit in CCR indicates a framing error ;* If C-bit is cleared, a framing error is indicated because ;* the STOP bit was detected as a 0 instead of a 1 ;* PTA0 configured as an input ;* SUBROUTINES CALLED: GetBit ;* VARIABLES READ: ;* VARIABLES MODIFIED: ;* STACK USED: 6 (including the call to this routine) ;* SIZE: 18 bytes ;* DESCRIPTION: EXECUTED OUT OF ROM Once called, program will remain in GetByte until a byte is ;* ;* received. Signal to start receiving a byte is a valid ;* (low) START bit. ;* This routine does not service COP. ;* NOTE: Cycle path for each bit reception must be kept the same to ;* maintain a steady baud rate. ;* When OSCSTAT[0]=0 (internal clock is selected): ;* 9+(28+10*38)= 417 cycles @ 4.0 MHZ=104.3 us=9592 bps ;* (closest PC baud rate 9,600 bps) ;* When OSCSTAT[0]=1 (external clock is selected): ;* 9+(27+10*22) = 256 cycles @ 2.4576 MHZ = 104 us = 9,600 bps brset 0,PTA,GetByte ;[.r...] loop till PTA0=0 (start) GetByte: ;[4+GetBit] check sense of start bit bsr GetBit ;[3] C-bit should be 0, else noise bcs GetByte lda #\$80 ;[2] Rx byte done when 1 RORs into C NextBit: top of loop to get 8 bits ; bsr GetBit ;[4+GetBit] sense level of next bit ;[1] rotate into A from left rora ;[1] pad to tune timing nop ;[3] continue 'till 1 RORs into C bcc NextBit stpBit: bsr GetBit ;[4+GetBit] sense level of stop bit rts ;[4] ;* NAME: PutByte ;* PURPOSE: Send one byte data through PTAO serially. This routine supports ;* ;* a baud rate 9600 bps at internal 4MHz and external 2.4576MHz bus ;* frequencies. A clock is distinguished by the state of ECGST bit ;* (bit 0) in OSCSTAT. When ECGST=1, an external clock is selected. ;* ENTRY CONDITIONS: PTA0 configured as an input, PTA0 data bit = 0 ;* ;* A contains data to be sent ;* EXIT CONDITIONS:

;* A and X is restored to entry values ;* PTA0 configured as an input (PTA0=high idle line) ;* SUBROUTINES CALLED: ;* VARIABLES READ: ;* VARIABLES MODIFIED: ;* STACK USED: 4 (including the call to this routine) ;* SIZE: 46 bytes ;* DESCRIPTION: EXECUTED OUT OF ROM After ~2 bit times delay, a character in A is sent via PTAO ;* Once called, program will remain in PutByte until PTAO=high ;* ;* This routine does not service COP PutByte: pshx ;[2] save X psha ;[2] temp save Tx data lda #10 ;[2] start, 8 data, stop = 10 loops ;[.r...] wait for PTA0 high (idle) brclr 0,PTA,* ;[2] load constant for Ext 1dx #BitX2 ;* delay ~2 bit times before transmitting data (time not critical) ;* Ext 2 bit is 25% longer and Int 2 bit is 23% shorter delay: dbnzx delay ;[3] loop 3 cyc * BitX2I ;[1] becomes stop bit after 9 RORs sec ;[3] Tx a low for start bit bra outLow PutLoop: 1,SP ;[5] LSB to C-bit, Tx that level ror outLow ;[3] if C=0 Tx low, else Tx high bcc outHi: ;[4] PTA0 input pulls up to high bclr 0,DDRA ;[3] go to time 1 bit delay bra outDelay outLow: bset 0,DDRA ;[4] PTA0 output makes pin drive low outDelay ;[3] time 1 bit delay (match time) bra outDelay: ldx OSCSTAT ;[3] check for Int/Ext clk ;[3] branch if Ext (OSCSTAT!=\$00) bne BitE ;[2] load Int bit delay 1dx #BitTimeI bra delOut ;[3] skip to delOut BitE: nop ;[1] timing adjust ldx #BitTimeE ;[2] load Ext bit delay ;[3] loop 3~ * (value in X) delOut: dbnzx delOut ;[1] timing adjust nop dbnza PutLoop ;[3] repeat for start, 8 data, stop pula ;[2] restore Tx data pulx ;[2] restore X ;[4] rts ;* NAME: GetBit ;* PURPOSE: ;* Receive one serial bit via PTAO and return it in C-bit ;* ENTRY CONDITIONS: ;* PTA0 configured as an input. ;* EXIT CONDITIONS: A and X is restored to entry values ;* ;* Bit level is returned to C bit in CCR ;* PTA0 configured as an input. ;* SUBROUTINES CALLED: GetBit ;* VARIABLES READ:

```
;* VARIABLES MODIFIED:
;* STACK USED: 4 (including the call to this routine)
;* SIZE: 31 bytes
;* DESCRIPTION: EXECUTED OUT OF ROM
;*
    Execution cycle for Internal and external is:
;*
     Internal (OSCSTAT[0]=0) = 28 + (10 x SampPerBitI)
     Extnernal (OSCSTAT[0]=1) = 27 + (10 \times \text{SampPerBitE})
GetBit:
            pshx
                                ;[2] preserve X
            psha
                                ;[2] preserve A
                                ;[1] time padding
            nop
            brset 0,OSCSTAT, SerialE ; [5] check if int or ext clk
            1da
                   #OffsetI
                              ;[2] # of samples to detect 1 (Int)
            1dx
                   #SampPerBitI ;[2] # of samples per bit (Int)
            brclr 0,OSCSTAT,loopIn; [5] time matching padding
SerialE:
            1da
                   #OffsetE
                              ;[2] # of samples to detect 1 (Ext)
            ldx
                   #SampPerBitE ;[2] # of samples per bit (Ext)
                                ;[1] time padding
            nop
                                ;[3] time padding
            bra
                   loopIn
loopIn:
            brclr
                  0,PTA,subSamp ;[5] set/clr C based on PTA0 level
subSamp:
                   #0
                                ;[2] subtract C from offset in A
            sbc
            dbnzx loopIn
                                ;[3] loop SampPerBitI times
            rola
                                ;[1] copy MSB to C bit (1 if A neg)
;* A would be negative if # of 1 samples was > OffsetG_
;* C bit reflects detected sense of current serial bit
            pula
                                ;[2] restore A
            pulx
                                ;[2] restore X
            rts
                                ;[4] return
;* NAME: RDVRRNG
;* PURPOSE: Read and/or verify a range of FLASH memory
;* ENTRY CONDITIONS:
    H:X contains a start address of the FLASH address range
;*
;*
    LADDR:LADDR+1 contains a last address of the FLASH address range
    The contents of A decides if read data is transferred serially
;*
;*
     via PTA0 (When A=0, PTA0 is used for serial transfer) or
;*
     the data is verified against the DATA array in RAM
;*
    DATA array contains the data to be verified
;*
    If A=0, PTA0 is configured as an input (DDRA0=0) and
;*
     data bit = 0 (PTA0=0)
;* EXIT CONDITIONS:
    A contains checksum
;*
;*
    C-bit in CCR indicates verify result when entry A is NOT zero
;*
     If C-bit is set, the verify is successful
;*
    DATA array contains read FLASH data when entry A is NOT zero
;*
    H:X contains a next FLASH read address
;* SUBROUTINES CALLED: PutByte
;* VARIABLES READ: LADDR:LADDR+1, DATA array
;* VARIABLES MODIFIED: DATA array
;* STACK USED: (include the call to this routine)
;*
    9 bytes for Verify operation (entry A is NOT zero)
;*
   11 bytes for data send out operation (entry A is zero)
;* SIZE: 67 bytes
;* DESCRIPTION: Executed out of ROM
    The COP is serviced in this routine. The first COP is serviced on
;*
```

```
;*
     23 bus cycles after this routine is called in the user software.
;*
     However, the COP timeout might still occur under the following
;*
     conditions:
;*
     1) COP is not serviced within a proper period in user software
;*
     2) COP set for short timeout and Read data is sent through PTA0
;* STACK FRAME:
;*
       SP+1
                  [G] SADDR(hi) temp storage
;*
       SP+2
                  [F] SADDR(lo) temp storage
;*
       SP+3 SP+1 [E] ByteCount - decrements to zero
;*
       SP+4 SP+2 [D] # of bad bytes - 0 on return means all were good
;*
       SP+5 SP+3 [C] Checksum - sum of all data values read
;*
       SP+6 SP+4 [B] Offset pointer into DATA array in RAM
;*
       SP+7 SP+5 [A] Verify/Read flag - 1=verify/0=read
;*
;*
                   +--reference label in square brackets
;*
               +---SP offset when SADDR not on stack
;*
         +----SP offset when SADDR on stack for temp storage
;*:
                                   ;verify(1)/Read(0) flag to Stack [A]
RDVRRNG:
             psha
             clra
             psha
                                   ;offset pointer into DATA array in
                                   ; RAM [B] (initially 0)
                                   ; increments from $00 to ByteCount
             psha
                                   ; initial Checksum to Stack [C]
                                   ;calculate total # of bytes
             txa
                                   ;SADDR(lo) -> A
             sub
                    LADDR+1
                                   ;SADDR(lo) - LADDR(lo) -> A
                                   ;LADDR(lo) - SADDR(lo) -> A
             nega
             inca
                                   ; change to 1-oriented vs 0-oriented
             psha
                                   ;# of bytes to Stack [D] (# of bad)
                                   ; decrements to zero if all good
             psha
                                   ;ByteCount to Stack [E]
                                   ; counter - decrements to zero
ReadData:
                    COPCTL
                                   ;service COP
             sta
             1da
                                   ;data from a FLASH location @ 0,X
                    , x
                                   ; check Read/Verify flag [A]
             tst
                    5,sp
             beq
                    Serial
                                   ;0 - send data through PTA0
                                   ;1 - verify against DATA in RAM
             pshx
                                   ; push SADDR(lo) to Stack [F]
             pshh
                                   ; push SADDR(hi) to Stack [G]
             ldx
                                   ;DATA array Pointer(lo) -> X
                    6,sp
             clrh
                                   ;H:X = 0:Pointer(lo)
             cmp
                    DATA, x
                                   ; compare FLASH data with DATA array
             bne
                    NoDataMatch
                                   ; if not equal, skip decrement of [D]
             dec
                    4,sp
                                   ;data matched so decrement # of bad
                    DATA, x
                                   ;replace DATA array value with
NoDataMatch: sta
                                   ; value read from FLASH
                                   ;restore SADDR(hi) pointer from [G]
             pulh
             pulx
                                   ;now H:X = SADDR, A is FLASH data
             bra
                    Checksum
                                   ;skip serial send if in Verify mode
Serial:
                    PutByte
                                   ;read mode so send data to host
             isr
Checksum:
             add
                    3,sp
                                   ;FLASH data + checksum [C] -> A
             sta
                    3,sp
                                   ;update checksum [C] on stack
             inc
                                   ;update offset into DATA array [B]
                    4,sp
```

aix #1 ;update pointer into FLASH (H:X) dec 1,sp ;decrement ByteCount [E] bne ReadData ;loop until ByteCount=0 ;deallocate [E] pula ;# of bad [D] -> A, and deallocate pula ; if Verify OK, A = \$00 ;\$00 -> \$FF if verify OK coma add ;\$FF -> \$00; C=1 if verify was OK #1 pula ;Checksum [C] -> A, and deallocate ;deallocate [A] and [B] ais #2 rts ;* RDVRRNG DONE ****************** ;* NAME: PRGRNGE ;* PURPOSE: Program a FLASH address range which is maximum 32 bytes in the ;* ;* same row. Bus frequency must be between 1.0MHz and 8.4MHz. ;* ENTRY CONDITIONS: H:X contains a start address of the FLASH address range ;* ;* LADDR:LADDR+1 contains a last address of the FLASH address range ;* DATA array contains the data to be programmed to the FLASH ;* (maximum 32 bytes) ;* CPUSPD contains a nearest integer of 4 x bus frequency (MHz) ;* EXIT CONDITIONS: ;* H:X contains a next FLASH address; I-bit set ;* SUBROUTINES CALLED: ;* VARIABLES READ: CPUSPD, LADDR:LADDR+1, DATA array ;* VARIABLES MODIFIED: LADDR(ByteCntr):LADDR+1(RamPntrLo) The values are modified, but they are restored with original ;* ;* values before exiting from this routine. ;* STACK SIZE: 9 bytes (including the call to this routine) ;* SIZE: 132 bytes ;* DESCRIPTION: EXECUTED OUT OF ROM ; * This routine can program the FLASH only in the same row. ;* Therefore, the total programing byte No. is maximum 32 bytes. ;* The COP is serviced in this routine. The first COP is serviced on ;* 59 bus cycles after this routine is called in the user software. ;* However, there could still be a COP time out if the COP is not ;* serviced within a proper period in user software. PRGRNGE: sei ;set I bit to mask interrupts lda LADDR psha ; save LADDR(hi) to stack [A] 1da LADDR+1 psha ; save LADDR(lo) to stack [B] pshx ;calculate total # of bytes ; to be programmed pula ;SLADDR (lo) -> A sub LADDR+1 ;SADDR(lo) - LADDR(lo) -> A nega ;LADDR(lo) - SADDR(lo) -> A inca ; change to 1-oriented vs 0-oriented ;[C] total remaining bytes to prog psha ; will decrement by LoopCOP on each

StartProg:

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; pass through LoopPROG

	clr	RamPntrLo	;start with 1st loc. in DATA array	
;* Current s	tack fr	rame		
;*			left to program; count down to zero	
;*	SP+3 [B] LADDR(lo) used to restore last addr before RTS			
;*	SP+4 [[A] LADDR(hi)		
; * * * * * * * * * * * * * * *	******	* * * * * * * * * * * * * * * * *	*********	
			ock of LoopCOP bytes are programmed	
			er loop. BSR PRGstep1 programs up to	
;* LoopCOP b	ytes be	etore return (la	ast batch may be fewer than LoopCOP)	
LoopPROG:	lda	1,sp	;[C] total bytes remaining to prog	
	beq	ProgEnd	; if zero, programing is done	
	cmp	#LoopCOP	;bytes remaining >= LoopCOP ?	
	bge	InitPROG	; if so, skip to InitPROG	
	sta	ByteCntr	;< so make ByteCntr = BytesRemaining	
	clr	1,sp	;and clear BytesRemaining at [C]	
	bra	Program	;Go program last partial block	
InitPROG:	sub	#LoopCOP	;>= so subtract LoopCOP	
	sta	1,sp	;bytes remaining reduced by LoopCOP	
	lda	#LoopCOP	;prepare to prog LoopCOP bytes	
	sta	ByteCntr	;ByteCntr = LoopCOP	
Program:	bsr	PRGstep1	;program up to LoopCOP bytes	
	bra	LoopPROG	;repeat outer loopcheck number of	
			;bytes remaining	
ProgEnd:	pula		;deallocate [C]	
	pula		, deallocate [C]	
	sta	LADDR+1	;restore an original value to LADDR+1	
	pula		-	
	sta	LADDR	;restore an original value to LADDR	
	rts			
;********	* * * * * * *	* * * * * * * * * * * * * * * *	**********	
;* FLASH Pro	-			
;*********	* * * * * * *	* * * * * * * * * * * * * * * *	* * * * * * * * * * * * * * * * * * * *	
PRGstep1:	sta	COPCTL	;[4] service COP	
-			; before programming ByteCntr bytes	
	lda	#mPGM	;[2]	
	sta	FLCR	;[w.] set PGM (Prog Algo Step 1)	
PRGstep2:	lda	FLBPR	;[4] read FLBPR (Prog Algo Step 2)	
_				
PRGstep3:	sta	, X	<pre>;[2] write to Flash address [H:X] ; w/ any data (Prog Algo Step 3)</pre>	
PRGstep4:	lda	CPUSPD	; W/ any data (FIOG AIGO Step 5) ;[3] delay for time Tnvs	
INGSCEP4.	dbnza	*	;[3*CPUSPD] (Prog Algo Step 4)	
	1.2			
PRGstep5:	lda		; sets HVEN and leaves PGM set	
	sta	FLCR	;[w.] set HVEN (Prog Algo Step 5)	
PRGstep6:	lda	CPUSPD	;[3] delay for time Tpgs	
-	dbnza	*	;[3*CPUSPD] (Prog Algo Step 6)	

;* Step 7 and Step 8 are repeated until a value in location LADDR+1 ;* reaches to zero. PRGstep7: ;[2] temp flash pointer (lo) [F] pshx pshh ;[2] temp flash pointer (hi) [G] ;* Current stack frame ;* SP+1 [G] flash pointer (hi) temp store so H:X available ;* SP+2 [F] flash pointer (lo) temp store so H:X available ;* SP+3 [E] PCH (return addr hi) ;* SP+4 [D] PCL (return addr lo) ;* SP+5 [C] bytes remaining to prog..not counting this block ;* SP+6 [B] LADDR+1 ;* SP+7 [A] LADDR clrh ;[1] clear upper half of H:X ldx ;[3] get DATA array pointer (lo) RamPntrLo lda DATA, x ;[3] read data from a DATA array pulh ;[2] restore flash pointer (hi) [G] ;[2] restore flash pointer (lo) [F] pulx ;[.w] write data to Flash addr sta , x (Prog Algo Step 7) ; ;* Compute Tprog based on bus speed ;* For slowest bus speeds (CPUSPD=4), Tprog = 38 bus cycles. For ;* other speeds, Tprog = 8 * CPUSPD + 5 bus cycles. PRGstep8: ;delay for Tprog (Prog Algo Step 8) 1da CPUSPD ;[3] cmp #4 ;[2] if CPUSPD=4 (bus = 1MHz), beq PRGstep9 ;[3] Tprog=38 cycles ;[1] for other cases asla ;[2] A = 2 x CPUSPD - 9 sub #9 DelayPRG: ;[1] 1~ delay nop ;[3] Tprog = 8 * CPUSPD + 5 cycles dbnza DelayPRG PRGstep9: (Prog Algo Step 9) ; aix #1 ;[2] point to next FLASH address inc RamPntrLo ;[4] increment DATA array pointer dec ByteCntr ;[4] decrement byte counter bne PRGstep7 ;[3] loop until byte counter is = 0 rol 1,sp ;[5] ROL/ROR/SEI makes 12~ delay 1,sp ;[5] to match delay to PRGstep10 ror ;[2] sei PRGstep10: lda #mHVEN ;[2] clear PGM, leave HVEN=1 FLCR (Prog Algo Step 10) sta ;[..w.] lda CPUSPD ;[3] delay for time Tnvh PRGstep11: dbnza ;[3*CPUSPD] (Prog Algo Step 11) PRGstep12: clra ;[1] pattern to clear HVEN sta FLCR ;[..w.] clear HVEN bit in FLCR

```
;clr HVEN (Prog Algo Step 12)
                 COPCTL
           sta
                              ;[4] service COP
                              ; [4]
           rts
;* NAME: DELNUS
;* PURPOSE: Generate delay (3 * A * X) + 5 [cycles]
;* ENTRY CONDITIONS:
;*
     A contains an integer value equal to 4 or higher
;*
     X contains an integer value equal to 1 or higher
;* STACK USED: 3 bytes (including the call to this routine)
;* SIZE: 10 bytes
;* DESCRIPTION: EXECUTED OUT OF ROM
    This routine is called from ERARNGE routines.
;*
;*
    For example when bus frequency = 4MHz, A=16, and X=17, the
;*
    delay time is:
;*
       delay time = (3 \times 16 \times 17) + 5 = 821 cycles (205.25us)
;*
       remember to consider delays associated with setup and JSR/BSR
DELNUS:
                              ;[1] A - 1
           deca
                              ;[2] temp save
Loop:
           psha
           deca
                              ;[1] original A - 2
                              ;[1] original A - 3
           deca
                              ;[3(orig A - 3)] (inner loop)
           dbnza
           pula
                              ;[2] recover original A - 1
           dbnzx Loop
                           ;[3] (bottom of outer loop)
;* outer loop = (X(2+1+1+(3(A-3))+2+3)) = (X(9+(3A-9)) = 3 * X * A)
           rts
                              ;[4]
;* NAME: ERARNGE
;* PURPOSE:
;* Erase a page or a whole array in FLASH memory. A bus frequency
;*
  range has to be between 1.0MHz and 8.4MHz.
;* ENTRY CONDITIONS:
   H:X contains an FLASH address within a page or an array to be
;*
;*
    erased
;*
   CTRLBYT selects MASS erase ($40) or PAGE erase ($00)
;*
    If other value is written to CTRLBYT, the erase operation
;*
    will not be performed
;*
   CPUSPD contains a nearest integer of 4 x bus frequency
;* EXIT CONDITIONS:
   The contents of H:X (address passed) is preserved; I-bit set
;*
;* SUBROUTINES CALLED: DELNUS
;* VARIABLES READ: CTRLBYT, CPUSPD
;* VARIABLES MODIFIED:
;* STACK USED: 7 (including the call to this routine)
;* SIZE: 76 bytes
;* DESCRIPTION: EXECUTED OUT OF ROM
;*
    Does not check for a blank range before (to see if erase is
;*
    necessary) or after (to see if successful erase). The COP is
;*
    serviced in this routine. The first COP is serviced on
;*
    (40+3xCPUSPD) bus cycles after this routine is called in the user
;*
    software. However, there could still be COP time out if the COP
```

·***********			r period in the user software. ************************************
ERARNGE:			
	lda	CTRLBYT	;if CTRLBYT is not either \$40 or
	and	#\$BF	; \$00, the operation is skipped
	bne	Finish	
	sei		;block interrupts during erase
	pshx		;temp save addr(lo) to free up X
ERAstep1:			
	lda	#mERASE	
	brclr	MASSBIT, CTRLB	YT,PageErase
			;if MASSBIT is set in the CTRLBYT,
	ora	#mMASS	; sets MASS and ERASE bits in A
PageErase:	sta	FLCR	;[w.] (Erase Algo Step 1)
			; set ERASE only, or MASS and ERASE
			, see hand only, of made and hand
ERAstep2:	lda	FLBPR	;[4] (Erase Algo Step 2)
ERAstep3:	sta	, X	;[.w] (Erase Algo Step 3)
			;latch addr for Flash page or block
ERAstep4:	lda	CPUSPD	;[3] delay Tnvs (Erase Algo Step 4)
шивсерт.	dbnza	*	; [3+(3*A)]
	ubiiza		,[J+(J A)]
ERAstep5:	lda	FLCR	;[4] leave MASS and ERASE as is
	ora	#mHVEN	;[2] set HVEN
	sta	FLCR	;[w.] (Erase Algo Step 5)
ERAstep6:			;delay Terase (Erase Algo Step 6)
-			;slit up to allow COP service
	lda	#LoopErase	;[2] initialize Loop Counter
		#пообытазе	;[2] Loop Count on stack for calcs
	psha		
			; using ' dec 1,sp' instruction
ServiceCOP:	sta	COPCTL	;[4] service COP
	ldx	#TERASE	;[2] about 200us delay
	lda	CPUSPD	;[3]
	bsr	DELNUS	;[4+(3*A*X)+5)]
	dec	1,sp	;[5] decrement Loop Counter
	bne	ServiceCOP	;[3] loop if Loop Count not zero
;* bottom of			, [5] TOOP IT DOOP COULD HOU ZELO
		-	
		-	HVEN=1 + loop + overhead to ERASE=0
;* = 5 + (EL	00PS(3*	A*X + 26)) + 1	5 33,180~ @8MHz (Terase=4.148mS)
	pula		;[2] deallocate Loop Counter
			; (Erase Algo Step 7)
	sta	COPCTL	;[4] service COP
ERAstep7:			
Liub cop / .	lda	FLCR	;[4]
	and #{\$FF-(mERASE+mMASS)}		
			;[2] clear ERASE and MASS bits
	sta	FLCR	;[w.] (Erase Algo Step 8)
			;[2]
ERAstep8:	ldx	#TNVHL	;delay for time Tnvhl
-	lda	CPUSPD	;[3] Tnvhl is used for both
	bsr	DELNUS	; page and mass erase
	~~-		; [4+(3*A*X)+5)] PAGE and MASS erase
			, [III A A A I J] I AGE ANA MASS ELASE

Notes

ERAstep9: clra			; (Erase Algo Step 9) ;[1] clear all bits in FLCR		
	sta	FLCR	;[w.]	next 3 instructions	
			; includ	ling last cycle of this	
			; instru	action make at least lus	
			; delay	for Trcv	
ERAstep10:			;	(Erase Algo Step 10)	
	pulx		;[2] red	cover original addr(lo)	
nsa			;[3] 3~	delay	
Finish:					
	rts		;[4] ret	curn from ERARNGE	
;* ERARNGE D	ONE ****	* * * * * * * * * * * * * * * *			

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